TOSHIBA Photocoupler IRED & Photo IC

TLP558

Isolated Bus Driver
High Speed Line Receiver
Microprocessor System Interfaces
MOS FET Gate Driver
Transistor Inverter

The TOSHIBA TLP558 consists of an infrared emitting diode and integrated high gain, high speed photodetector.

This unit is 8-lead DIP package.

The detector has a three state output stage that provides source drive and sink drive, and built-in schmitt trigger. The detector IC has an internal shield that provides a guaranteed common mode transient immunity of 1000V / µs. TLP558 is inverter logic type. For buffer logic type, TLP555 is in line-up.

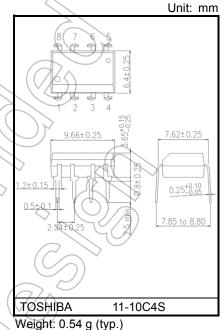
- Input current: IF=1.6 mA (max)
- Power supply voltage: VCC=4.5 to 20 V
- Switching speed: tpHL, tpLH=400ns (max)
- Common mode transient immunity: ±1000V/µs (min)/
- Guaranteed performance over temperature: -25 to 85°C
- Isolation voltage: 2500Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service

No.5A File No.E67349

Truth Table

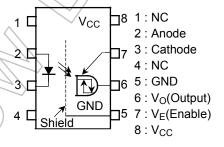
Input	Enable	Output
Н	H	
L	Н	Н
Н	Ĺ	Z
L	⟨\Q	Z

A $0.1\mu F$ bypass capacitor must be connected between pins 8 and 5.

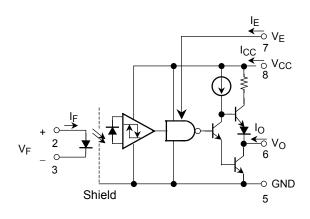


Weight. 0.54 g (typ.)

Pin Configuration (top view)



Schematic



Start of commercial production 1987-05

Absolute Maximum Ratings

	Charactersitic		Symbol	Rating	Unit
	Forward current		lF	10	mA
	Peak transient forward current	(Note 1)	IFPT	1	Α
쁘	Reverse voltage		VR	5	V
	Diode power dissipation		P_{D}	45	mW
	Output current		lo	40 / -25	mA
	Peak output current	(Note 2)	lop	80 / -50	mA
	Output voltage		⟨Vo (-0.5 to 20	V
or	Supply voltage		Vcc	-0.5 to 20	V
Detector	Three state enabel voltage		VE	-0.5 to 20	V
۵	Output power dissipation		Po	100	mW
	Output power dissipation derating (Ta > 70 °C)	<	ΔΡΟ/ΔΤα	-1.8	mW/°C
	Total package power dissipation	6	Рт	200	mW
	Total package power dissipation derating (Ta > 70 °C)		ΔΡΤ/ΔΤα	-3.6	mW/°C
Оре	erating temperature range		T _{opr}	-40 to 85	/,c
Sto	Storage temperature range			-55 to 125	°C
Lea	d solder temperature(10 s)	(Note 3)	T _{sol}	260	°C
Isol	ation voltage (AC, 60 s, R.H. ≤ 60 %, Ta=25°C)	BVs	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width \leq 1 µs, 300 pps.
- Note 2: Pulse width $\leq 5\mu$ s, duty ratio ≤ 0.025 .
- Note 3: 1.6 mm below seating plane.
- Note 4: Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Input current, on	I _{F(ON)}	2 (Note 1)	_	5	mA
Input voltage, off	VF(OFF)	0	_	0.8	V
Supply voltage	Vcc	4.5	_	20	V
Enable voltage high	VEH	2.0	_	20	V
Enable voltage low	V _{EL}	0	_	0.8	V
Fan out(TTL load)	N	_	_	4	_
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: 2 mA condition permits at least 20 % CTR degradation guardband. Initial switching threshold is 1.6 mA or less.



Electrical Characteristics (unless otherwise specified, Ta = -25 to 85°C, Vcc = 4.5 to 20V)

Characteristic	Symbol	Test (Min	Тур.	Max	Unit	
Input forward voltage	V _F	I _F = 5 mA, Ta =	_	1.55	1.7	V	
Temperature coefficient of forward voltage	ΔV _F / ΔTa	IF = 5 mA	_	-2.0	_	mV / °C	
Input reverse current	I _R	V _R = 5 V, Ta = 2	5 °C	-	_	10	μΑ
Input capacitance	Ст	V _F = 0 V, f = 1 M	1Hz, Ta = 25 °C	+(45	ı	pF
Output leakage current	Іонн	V	V _O = V _E = 5.5 V			100	μA
(Vo > Vcc)	IONN	V _{CC} = 4.5 V	V _O = V _E = 20 V	(//-5)	0.01	500	μΛ
Logic low output voltage	VoL	I _{OL} = 6.4 mA, I _F V _E = 2 V	= 1.6 mA		0.4	0.5	٧
Logic high output voltage	Voн	I _{OH} = -2.6 mA, V _E = 2 V	/F = 0.8 V	2.4	3.3	_	V
Logic low enable current	lEL	VE = 0.4 V	4/ >	_	-0.13	-0.32	mA
		VE = 2.7 V	V _E = 2.7 V			> 20	
Logic high enable current	IEH	V _E = 5.5 V		♦- ($\mathcal{O}_{\mathcal{I}_{\mathcal{I}_{\mathcal{I}}}}$	100	μΑ
		V _E = 20 V			0.01	250	
Logic low enable voltage	VEL			(4	<u> </u>	0.8	V
Logic high enable voltage	VEH		$\stackrel{\searrow}{}$	2.0	/ —	_	V
Logic low supply current	Iccl	IF = 5 mA	$V_{CC} = V_E = 5.5 V$	74	4.0	6.0	mA
			Vcc = VE = 20 V	J}	4.6	7.5	
Logic high supply current	Іссн	VF = 0.V	$V_{CC} = V_E = 5.5 \text{ V}$	_	4.2	6.0	mA
		7. 4.	V _{CC} = V _E = 20 V	_	4.7	7.5	
	IOZL	V _E = 0 V V _E = 0.8 V	V _O = 0.4 V	_	_	-20	
High impedance state output current	lozh	I _F = 5 mA V _E = 0.8 V	Vo = 2.4 V	_	_	20	μΑ
			V _O = 5.5 V	_	_	100	
			V _O = 20 V	_	1	500	
Logic low short circuit	Jost	NF = 5 mA	V _O = V _{CC} = 5.5 V	25	55	_	mA
output current (Note 1)	1032	VE = 2 V	V _O = V _{CC} = 20 V	40	80	_	110.
Logic high short circuit	Iosh	VF = 0 V, VO = 0	OND VCC = 5.5 V	-10	-25	_	- mA
output current (Note 1)	IOSH	V _E = 2 V	V _{CC} = 20 V	-25	-60	_	
Input current logic low output	IFD	V _E = 2 V, I _O = 6. V _O < 0.4 V	_	0.4	1.6	mA	
Input voltage logic high output	VFH	VE = 2 V, I _O = -2.6 mA V _O > 2.4 V		0.8	_	_	V
Input current hysteresis	IHYS	V _C C = V _E = 5 V	_	0.05	ı	mA	
Resistance (input-output)	Rs	V _S = 500 V, R.H Ta = 25 °C	5×10 ¹⁰	10 ¹⁴	_	Ω	
Capacitance(input-output)	Cs	V _S = 0 V, f = 1 N	1Hz, Ta = 25 °C (Note 2)	_	1.0	_	pF

Note: All typical values are at Ta = 25 °C, VCC = 5 V, IF(ON) = 3 mA unless otherwise specified.

Note 2: Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Note 1: Duration of output short circuit time should not exceed 10 ms.

Switching Characteristics (unless otherwise specified, Vcc = 4.5 to 20V, Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time to logic high output	(Note 1)	t _{pLH}		I _F = 3→ 0 mA	_	250	400	ns
Propagation delay time to logic low output	(Note 1)	t _{pHL}	1	I _F = 0→ 3 mA		270	400	ns
Output rise time (10-90%)		tr		I _F = 3→ 0 mA, V _{CC} = 5 V	+	35	75	ns
Output fall time (90-10%)		t _f		I _F = 0→ 3 mA, V _{CC} = 5 V		20	75	ns
Common mode transient immunity at logic high output	(Note 2)	Смн		I _F = 0 mA, V _{CM} = 50 V V _O (Min) = 2 V	1000	_	-	V / µs
Common mode transient immunity at logic low output	(Note 2)	Смь	3	I _F = 1.6 mA, V _{CM} = 50 V V _{O (Max)} = 0.8 V	-1000	_	-	V / µs

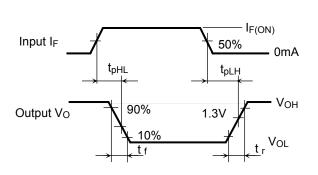
Note: All typical values are at Ta = 25 °C, Vcc = 5 V

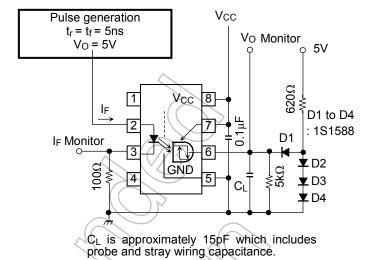
- Note: A ceramic capacitor (0.1 µF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.
- Note 1: The tpLH propagation delay is measured from the 50 % point on the trailing edge of the input pulse to the 1.3 V point on the leading edge of the output pulse. The tpHL propagation delay is measured from the 50 % point on the leading edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.
- Note 2: CML is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (VO < 0.8 V).

CMH is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic state (VO > 2.0 V).

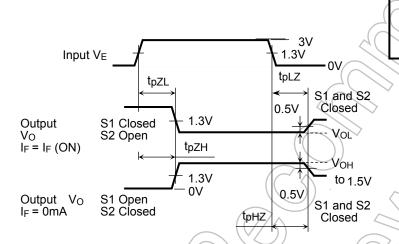


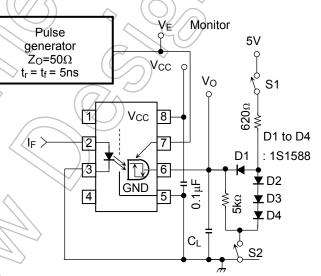
Test Circuit 1: tplh, tphl, tr and tf





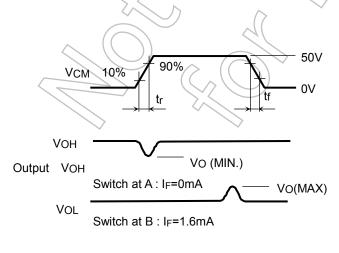
Test Circuit 2: tpHz, tpZH, tpLz and tpZL



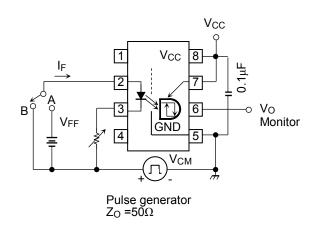


C_L is approximately 15_pF which includes probe and stray wiring capacitance.

Test Circuit 3: Common Mode Transient Immunity



$$CMH = \frac{45(V)}{tf(\mu s)}, CML = \frac{45(V)}{tf(\mu s)}$$



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
 equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to
 control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative or contact us via our website.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
 Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
 substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for High Speed Optocouplers category:

Click to view products by Toshiba manufacturer:

Other Similar products are found below:

HCPL-2201-300 TLP558(F) JAN4N24 610737H HCPL2630M HCPL2731SM HCPL2630SM PS9817A-1-F3-AX EL816S2(C)(TU)-F TLP290(V4GBTP,SE(T PS9121-F3-AX PS9123-F3-AX HCPL2531S HCPL2631SD HCPL-4661-500E TLP118(TPL,E) TLP621-2XGB 4N46-300E JANTXV4N24U SFH6318T 6N135-300E TIL198 TLP2309(TPL,E) TLP2355(TPL,E TLP521-4GR TLP521-4XGB TLP621-4X TLP621XSM IS281-4GB IS181GR ICPL2631 ICPL2630 ICPL2531 ICPL2601 TLP2301(E(T TLP714(F) TLP754(F) FOD260LSDV ACPL-M21L-500E ACPL-064L-500E PS2501-1XSM PS2505-1 PS2561L2-1-F3-A PS2913-1-F3-AX PS9821-2-F3-AX FOD0721R2 FODM8061R2V 6N135SDM 6N137SDM 6N138-000E